# ML3303

# modulight

#### 780 nm DBR laser

ML3303 is a 780 nm Distributed Bragg Reflector single-frequency laser diode. It has a monolithic structure with separate gain and grating sections. The epitaxial structure is grown on Gallium Arsenide (GaAs) substrate, and the vertical and horizontal waveguide designs have been optimized for fundamental mode emission over a wide operating range. The Bragg grating locks the emission to a single frequency. Laser design has been optimized for narrow emission linewidth.



## **Recommended Operating Conditions**

Conditions under which the parameters listed in "Opto-electrical characteristics" will be met.

Parameter	Symbol	Min	Max	Unit
Submount temperature	Tc	15	30	°C
Operating Current	I <sub>OP</sub>	-	250	mA

# **Electro-Optical Characteristics (BOL)**

Unless otherwise indicated, the parameters given in the table below are valid for the whole operating temperature range.

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Peak Wavelength	λ <sub>P</sub>	779.7	780.2	780.7	nm	T <sub>c</sub> = 25°C
Laser Linewidth (FWHM)	Δλ	-	400	800	kHz	Range 100-250 mA, T <sub>c</sub> = 25°C
Side Mode Suppression Ratio	SMSR	40	45	-	dB	
Wavelength temperature coefficient	dλ/dT	-	0.05	-	nm/°C	
Wavelength current coefficient	dλ/dI	-	0.002	-	nm/mA	
Threshold Current	Ітн	-	45	70	mA	
Optical output power@max lop	P <sub>OP</sub>	130	150	-	mW	I <sub>OP</sub> = 250 mA
Operating voltage@max lop	V <sub>OP</sub>	-	2	2.2	V	I <sub>OP</sub> = 250 mA
Slope efficiency	η	-	0.8	-	mW/mA	
Series resistance	Rs	-	1.9	-	Ohm	
Horizontal/parallel beam divergence	θн	-	6	-	۰	FWHM
Vertical/perpendicular beam divergence	θν	-	27	-	0	FWHM
Mode structure						
Laser polarization	TM					



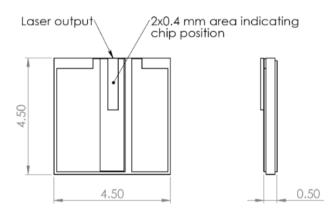
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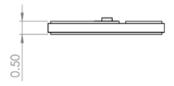
# **Absolute Maximum Ratings**

Values should not be exceeded in any conditions to avoid permanent device damage.

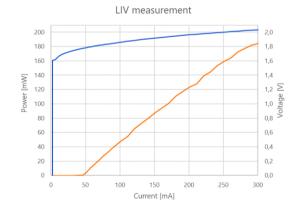
Parameter	Symbol	Min	Max	Unit
Submount temperature	T <sub>C</sub>	5	45	°C
Storage temperature	Ts	5	60	°C
LD forward current	I <sub>LD</sub>	-	400	mA
LD reverse voltage	$V_{RLD}$	-	0	V

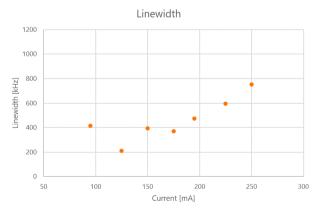
# **Mechanical Specification**





# **Typical Performance**





#### **Safety Information**

- ☐ Laser light may permanently damage the human eye. These lasers should be operated only by personnel familiar with laser safety requirements.
- ☐ These Modulight products are not intended for use in systems where product malfunction can reasonably be expected to result in personal injury.



Peak power and wavelength are for safety analysis only, not to present device performance.

ATTENTION

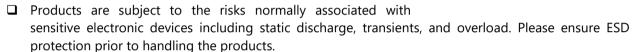
OBSERVE PRECAUTIONS FOR HANDLING

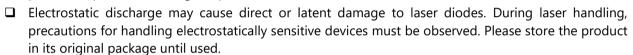
ELECTROSTATIC

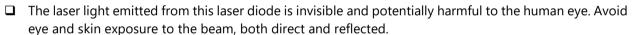
DEVICES

#### Handling

- □ DBR lasers are sensitive to optical feedback, thus optical isolator may be required in order to reach the specified performance.
- ☐ Laser chips are sensitive both mechanically and electrically. Extreme care should be taken when handling the bare dies, in order to avoid any damage to laser facets and waveguide area.







### Liability note

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#### **RoHS** compliance

The product complies with EU RoHS 2 (Directive 2011/65/EU) and China RoHS II (Management Methods for the Restriction of the Use of Hazardous Substances in Electrical and Electronic Products)



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